NSN 5961-00-552-8170

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-552-8170 **Inclosure Material:** Metal **Overall Length:** 0.405 inches **Overall Diameter:** 0.424 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.424 inches and 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 reverse voltage, peak **Current Rating Per Characteristic:** 10.00 amperes zero-gate-voltage source current any acceptable **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius case **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud **Specification Data:** 80131-release2026 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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